Symmetrical Gate Turn-Off Thyristor Type SA25AP1200FY



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SA	25	AP	1200	F	Y		
-	Voltage Code	Outline Code	Current code	Type code	Special code	Optional code	



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Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V _{DRM}	Repetitive peak off-state voltage, (note 1)	2500	V
V _{RSM}	Non-repetitive peak off-state voltage, (note 1)	2600	V
V _{RRM}	Repetitive peak reverse voltage	100	V
V _{RSM}	Non-repetitive peak reverse voltage	100	V
note 1)	$V_{GK} = -2V$		

	OTHER RATINGS	MAXIMUM LIMITS	UNITS			
I _{TGQ}	Peak turn-off current (note 1)	1200	А			
L _S	Snubber loop impedance, $I_{TM} = I_{TGQ}$ (note 1)	0.3	nH			
I _{T(AV)M}	Mean on-state current, T _{sink} = 55°C, (note 2)	790	А			
I _{T(RMS)}	Nominal RMS on-state current, T _{sink} = 25°C (note 2)	1600	А			
I _{TSM}	Peak non-repetitive surge current t _p = 10ms	13.0	kA			
I _{TSM2}	Peak non-repetitive surge current (note 3)	23.0	kA			
l ² t	$I^{2}t$ capacity for fusing t_{p} = 10ms	840 · 10 ³	A ² s			
(di/dt) _{cr}	Critical rate of rise of on-state current, (note 4)	1000	A/µs			
P _{FGM}	Peak forward gate power	200	W			
P _{RGM}	Peark reverse gate power	8	kW			
I _{FGM}	Peak forward gate current	140	А			
V _{RGM}	Peak reverse gate voltage (note 5)	18	V			
t _{off}	Minimum permissible off-time, $I_{TM} = I_{TGQ}$ (note 1)	80	μs			
t _{on}	Minimum permissible off-time	20	μs			
Т _{јор}	Operating temperature range	-40 to +125	°C			
T _{stg}	Storage temperature range	-40 to +150	°C			
note 1)	T_{j} = 125°C, V_{D} = 80% $V_{DM}, V_{DM} \leq V_{DRM}, di_{GQ}/dt$ = 20A/µs, I_{TM} = I_{TGQ} and G	C _S = 3μF				
note 2)	Double-side cooled, single phase, 50Hz, 180° half-sinewave.					
note 3)	Half-sinewave, t _p = 2ms					
note 4)	For di/dt > 1000A/µs please consult factory.					
note 5)	May exceed this value during turn-off avalanche period.					

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Characteristics

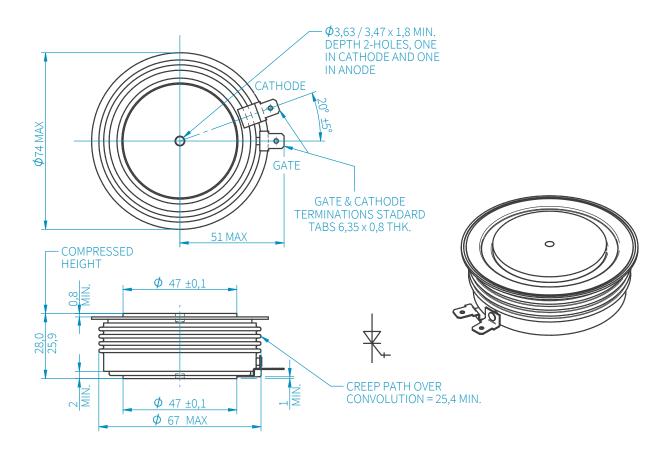
	PARAMETER	TEST CONDITIONS	MIN	ТҮР	МАХ	UNITS
V _{TM}	Maximum peak on-state voltage $I_G = 2A, I_T = 1200A$		-	2.4	2.7	V
IL	Latching current	T _i = 25°C	-	10	-	А
Ι _Η	Holding current	1j - 25 C	-	10	-	А
(dv/dt) _{cr}	Critical rate of rise of off-state voltage	$V_{D} = 80\% V_{DRM}, V_{GR} = -2V$	1000	-	-	V/µs
I _{DRM}	Peak off-state current	Rated V_{DRM} , $V_{GR} = -2V$	-	-	50	mA
I _{RRM}	Peak reverse current	Rated V _{RRM}	-	-	100	mA
I _{GKM}	Peak negative gate leakage current	$V_{GR} = -16V$	-	-	200	mA
		T_j = -40°C, V_D = 25V, R_L = 25m Ω	-	1.0	-	V
V _{GT}	Gate trigger voltage	T_j = 25°C, V_D = 25V, R_L = 25m Ω	-	0.9	-	V
		T_j = 125°C, V_D = 25V, R_L = 25m Ω	-	0.8	-	V
		T_j = -40°C, V_D = 25V, R_L = 25m Ω	-	2	7	А
I_{GT}	Gate trigger current	$T_{j} = 25^{\circ}C, V_{D} = 25V, R_{L} = 25m\Omega$	-	0.5	2	А
		T_j = 125°C, V_D = 25V, R_L = 25m Ω	-	50	300	mA
t _d	Delay time	(note 2)	-	1.5	-	μs
t _{gt}	Turn-on time	Conditions as for $t_d,$ (10%I_{GM} to 10%V_D $$	-	4.5	8.0	μs
t _f	Fall time	(note 3)	-	1	-	μs
t _{gq}	Turn-off time	Conditions as for $t_f,(10\% I_{GQ}to10\% I_{TGQ}$	-	19	22	μs
I _{GQ}	Turn-off gate current	Conditions as for t _f	-	300	-	А
Q_{GQ}	Turn-off gate charge		-	4000	5000	mC
t _{tail}	Tail time	Conditions as for t _f , (10%I _{TGQ} to I _{TGQ} < 1A	-	50	75	μs
t _{gw}	Gate off-time (note 4)	Conditions as for t _f	150	-	-	μs
		Double side cooled	-	-	0.027	kW
R _{thJK}	Thermal resistance, junction to sink	Cathode side cooled	-	-	0.070	kW
		Anode side cooled	-	-	0.045	kW
F	Mounting force	(note 5)	15	-	25	kN
W _t	Weight		-	480	-	g
note 1)	Unless otherwise indicated T _j = 125°C					
note 2)	$V_D = 50\% V_{DRM}$, $I_{TGQ} = 1200A$, $I_{GM} = 20A$, $di_G/dt = 10A/\mu s$, $T_j = 25^{\circ}C$, $di/dt = 300A/\mu s$, $(10\% I_{GM} to 90\% V_D)$					
note 3)	$V_D = 50\% V_{DRM}$, $I_{TGQ} = 1200A$, $C_S = 3\mu$ F, $di_G/dt = 20A/\mu s$, $V_{GR} = -16V$, (90% I_{TGQ} to 10% I_{TGQ})					
note 4)	The gate off-time is the period during which the gate circuit is required to remain low impedance to allow for the passage of tail current.					
note 5)	For other clamping forces, consult factory.					

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Outline Drawing





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